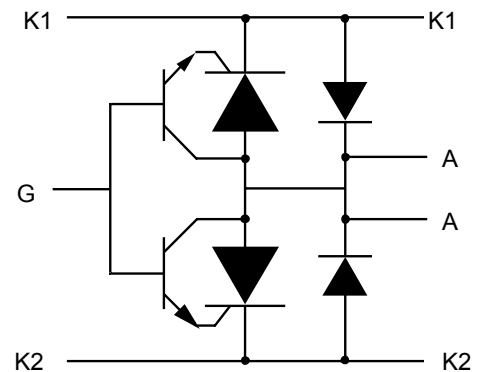
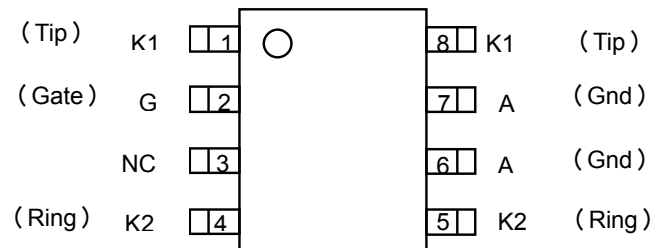
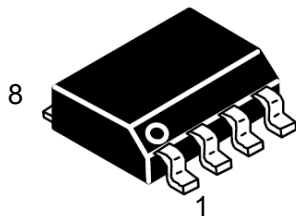


## Description

This device is especially designed to protect Subscriber Line Interface Circuit (SLIC) against transient overvoltage. Positive overloads are clipped with 2 diodes. Negative surges are suppressed by 2 Thyristors, their breakdown voltage being referenced to  $V_{BAT}$  through the gate. This component presents a very low gate triggering current and minimizes overvoltage stress on the SLIC.



## SOP Package Top View and Device Symbol

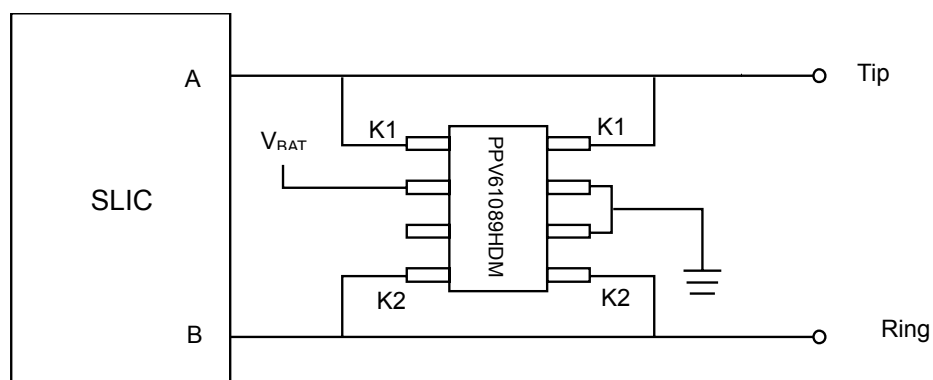


## Feature

- Dual programmable transient suppressor
- Wide battery voltage supports
- Low gate triggering current
- High holding current
- ESD Immunity(HBM): JESD22 Class 3B,  $\geq 8KV$
- MLS: Lever 1 – unlimited

## Applications

- Switch Line Card
- Access Network Card
- PBX's and other switches
- Set-top box
- VoIP.



## Telecom standards

- ITU-T K.20/21/45

Rated for LSSGR '1089 Conditions 2/10 Overshoot Voltage Specified

'1089 TEST		Voltage waveform ( $\mu$ s)	Required peak current(A)
Section	Test #		
4.5.7 4.5.8	4 1	2/10 $\mu$ s	350
4.5.7	1,3	10/1000 $\mu$ s	70

'1089 TEST		60 Hz power fault time	Required peak current(A)
Section	Test #		
4.5.12	9	500ms	6.5
4.5.12	3,4,8	1s	4.6
4.5.12 4.5.13	5 2,3	5s	2.3
4.5.12	6	30s	1.3
4.5.12 4.5.13 4.5.15/16	1,2 1,4,5	900s	0.73

## Absolute Maximum Ratings

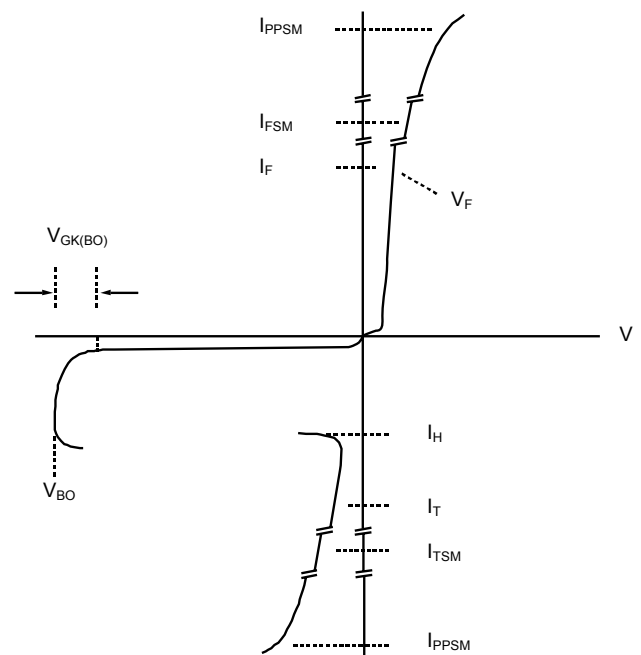
Symbol	Parameter	Value	Unit
$I_{pp}$	Non-repetitive peak on-state pulse current 10/1000 $\mu$ s 5/310 $\mu$ s 2/10 $\mu$ s	70 100 350	A
$I_{TSM}$	Non repetitive surge peak on-state current (sinusoidal) 60Hz 0.5s 1s 5s 30s 900s	7.2 5.3 3.0 2.1 1.65	A
$V_{DRM}$	Maximum voltage LINE/GROUND	-170	V
$V_{GKRM}$	Maximum voltage GATE/LINE	-167	V
$T_A$	Operating free-air temperature range	-40-85	°C
$T_{STG}$	Storage temperature range	-40-150	°C
$T_J$	Junction temperature	-40-150	°C
$T_L$	Maximum lead temperature for soldering during 10S	260	°C

## Thermal Resistance

Symbol	Parameter	Value	Unit
$R_{\theta JA}$	Junction to free air thermal resistance	120	°C/W

## Electrical Characteristics (Tamb=25°C)

Symbol	Parameter
$I_D$	Off-state current
$I_H$	Holding current
$V_{BO}$	Breakover voltage
$V_F$	Forward voltage
$V_{FRM}$	Peak Forward Recovery voltage
$V_{GK(BD)}$	Gate-cathode impulse breakover voltage
$I_{GKS}$	Gate reverse current
$I_{GT}$	Gate trigger current
$V_{GT}$	Gate-cathode trigger voltage
$C_{KA}$	Cathode-anode off-state capacitance



## Parameters Related to The Diode (Tamb=25°C)

Parameter		Test conditions	Min.	Typ.	Max.	Unit.
$V_F$	forward voltage	$I_F=5A$ , $t_w=200\mu s$			3	V
$V_{FRM}$	peak forward recovery voltage	$2/10\mu s$ , $I_F=100A$ , $R_s=50\Omega$ , $di/dt=80A/\mu s$			10	V

## Parameters Related to The Protection Thyristor (Tamb=25°C)

Parameter	Test conditions	Min.	Typ.	Max.	Unit.
$I_D$ off-state current	$V_D=-170V$ , $V_{GK}=0$	$T_J=25^\circ C$		-5	$\mu A$
		$T_J=85^\circ C$		-5	$\mu A$
$V_{BO}$ breakover voltage	$2/10\mu s$ , $I_{TM}=100A$ , $R_s=50\Omega$ , $di/dt=-80A/\mu s$ , $V_{GG}=-100V$			-112	V
$I_H$ holding current	$I_T=-1A$ , $di/dt=1A/ms$ , $V_{GG}=-100V$	-150			mA
$I_{GAS}$ gate reverse current	$V_{GG}=V_{GK}=-167V$ , $V_{KA}=0$	$T_J=25^\circ C$		-5	$\mu A$
		$T_J=85^\circ C$		-5	$\mu A$
$I_{GT}$ gate trigger current	$I_T=3A$ , $tp(g)\geq 20\mu s$ , $V_{GG}=-100V$			5	mA
$V_{GT}$ gate trigger voltage	$I_T=3A$ , $tp(g)\geq 20\mu s$ , $V_{GG}=-100V$			2.5	V
$C_{KA}$ anode-cathode offstate capacitance	$f=1MHz$ , $V_d=1V$ , $I_G=0$	$V_D=-3V$		110	pF
		$V_D=-48V$		55	pF

## Thermal information (Tamb=25°C)

Non-Repetitive Peak On-state Current against Duration

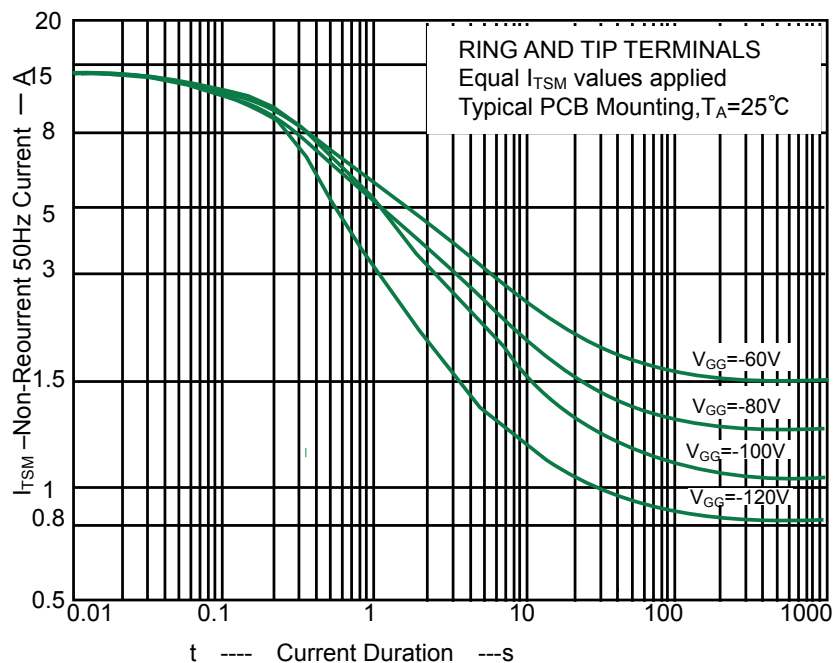
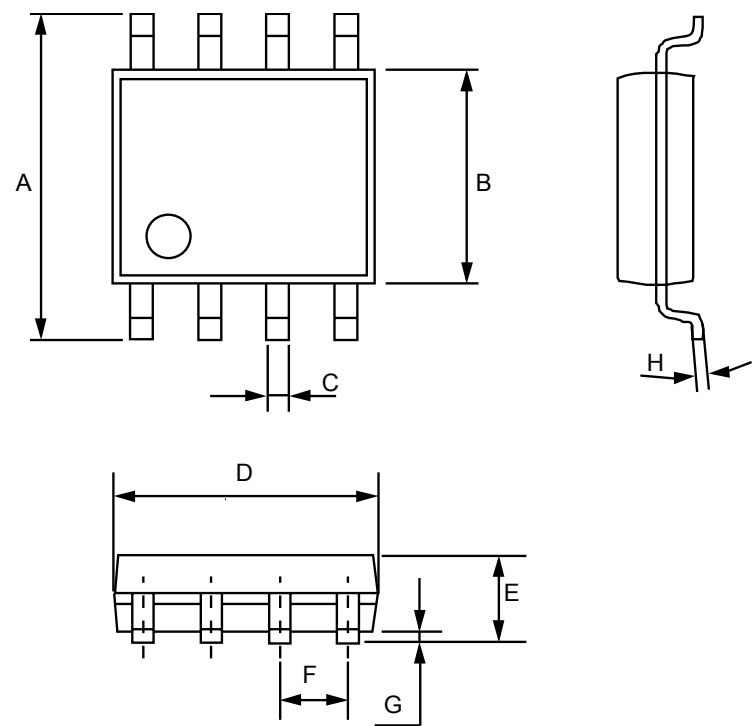



Fig 1 Non-Repetitive Peak On-State Current against Duration

Product dimension (SOP-8)



Dim	Millimeters		Inches	
	MIN	MAX	MIN	MAX
A	5.800	6.200	0.228	0.244
B	3.800	4.000	0.150	0.157
C	0.330	0.510	0.013	0.020
D	4.700	5.100	0.185	0.200
E	1.350	1.750	0.053	0.069
F	1.270 (BSC)		0.050 (BSC)	
G	0.100	0.250	0.004	0.010
H	0.170	0.250	0.006	0.010


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